International Rectifier

MB SERIES

SINGLE PHASE BRIDGE

Power Modules

Features

- Universal, 3 way terminals: push-on, wrap around or solder
- High thermal conductivity package, electrically insulated case
- Center hole fixing
- Excellent power/volume ratio
- UL E 62320 approved **S**
- Nickel plated terminals solderable as per MIL-STD-202 Method 208; solder: Sn/Pb (60/40); solder temperature: 235-260°C max. time: 8-10 secs

25 A 35 A

Description

A range of extremely compact, encapsulated single phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications.

Major Ratings and Characteristics

Parameters		26MB-A	36MB-A	Units	
Io		25	35	А	
	@ T _C	65	60	°C	
I _{FSM}	@ 50Hz	400	475	А	
	@ 60Hz	420	500	А	
I ² t	@ 50Hz	790	1130	A ² s	
	@ 60Hz	725	1030	A ² s	
V _{RRM} range		200 t	V		
Т		- 55	°C		

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V _{RRM} , maximum repetitive peak reverse voltage	V _{RSM} , maximum non- repetitive peak rev. voltage	I _{RRM} max. @ T _J max.
		V	V	
	20	200	275	
	40	400	500	
26MBA	60	600	725	2
36MBA 80		800	900	
	100	1000	1100	
	120	1200	1300	

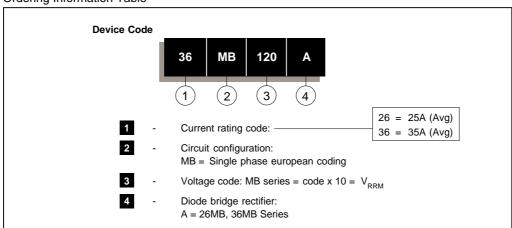
Forward Conduction

	Parameters	26MB-A	36MB-A	Units	Condition	ons	
I O Maximum DC output current		25	35	Α	Resistive or inductive load		nd
		20	28	Α	Capacitive	e load	
	@ Case temperature	65	60	°C			
I _{FSM}	Maximum peak, one-cycle	400	475	Α	t=10ms	No voltage	
	non-repetitive forward current	420	500		t=8.3ms	reapplied	
		335	400		t=10ms	100% V _{RRM}	
		350	420		t=8.3ms	reapplied	Initial $T_j = T_j max$.
l²t	Maximum I2t for fusing	790	1130	A ² s	t=10ms	No voltage	
		725	1030		t=8.3ms	reapplied	
		560	800		t=10ms	100% V _{RRM}	
		512	730		t=8.3ms	reapplied	
I²√t	Maximum I²√t for fusing	5.6	11.3	KA²√s	I^2 t for time $t_v = I^2 \sqrt{t} \times \sqrt{t_v}$;		
					$0.1 \le t_x \le 10 \text{ms}, V_{RRM} = 0 \text{V}$		
V _{F(TO)1}	Low-level of threshold voltage	0.76	0.79	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), @ T_{J} max.$		
V _{F(TO)2}	High-level of threshold voltage	0.92	0.96		$(I > \pi x I_{F(AV)}), @ T_{J} max.$		
r _{t1}	Low-level forward slope resistance	6.8	5.8	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, @ T_J max.		
r _{t2}	High-level forward slope resistance	5.0	4.5]	$(I > \pi \times I_{F(AV)})$, @ T_J max.		
V _{FM}	Maximum forward voltage drop	1.11	1.14	V	$T_J = 25 ^{\circ}\text{C}, I_{FM} = 40A_{PK}(26\text{MB})$		
					$I_J = 25 ^{\circ}\text{C}, I_{FM} = 40 A_{PK} (26 MB)$ $I_J = 25 ^{\circ}\text{C}, I_{FM} = 55 A_{PK} (36 MB)$ tp = 400 \(\mu\)s		
I _{RRM}	Max. DC reverse current	10	10	μΑ	T _J =25 °C, per diode at V _{RRM}		
V _{INS}	RMS isolation voltage base plate	2700	2700	V	f=50 Hz, t=1s		

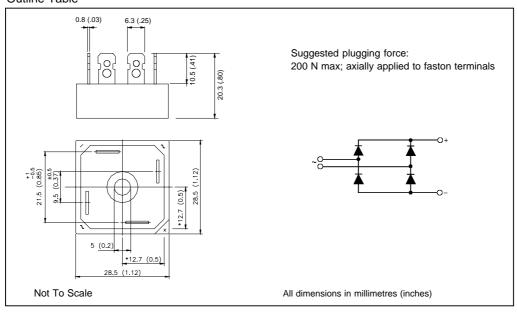
Thermal and Mechanical Specifications

	Parameters	26MB-A	36MB-A	Units	Conditions
T_J	Junction temperature range	-55 to 150 °C			
T _{stg}	Storage temperature range	-55 to 150 °C			
R _{thJC}	Max. thermal resistance junction to case	1.7	1.2	K/W	Per bridge
R _{thCS}	Max. thermal resistance, case to heatsink	0.2		K/W	Mounting surface, smooth, flat and greased
wt	Approximate weight	20		g	
Т	Mounting Torque ± 10%	2.0		Nm	Bridge to heatsink

Ordering Information Table



Outline Table



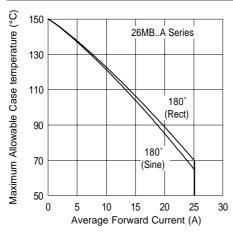


Fig. 1 - Current Ratings Characteristics

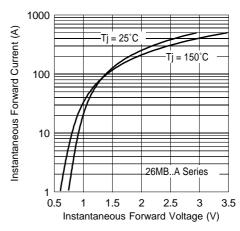


Fig. 2 - Forward Voltage Drop Characteristics Maximum Allowable Ambient Te

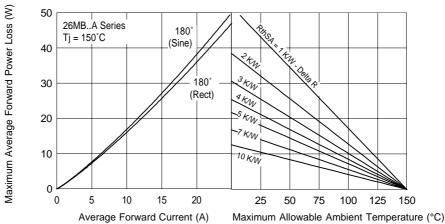


Fig. 3 - Total Power Loss Characteristics

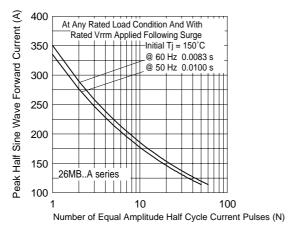


Fig. 4 - Maximum Non-Repetitive Surge Current

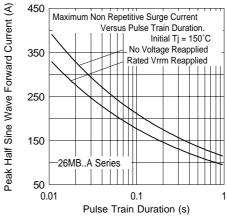


Fig. 5 - Maximum Non-Repetitive Surge Current

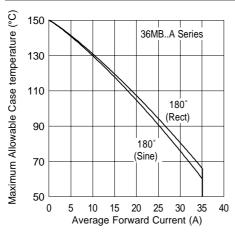


Fig. 6 - Current Ratings Characteristics

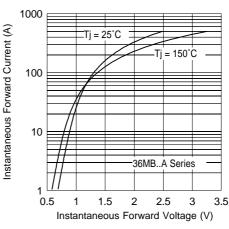


Fig. 7 - Forward Voltage Drop Characteristics

Maximum Allowable Ambient Te

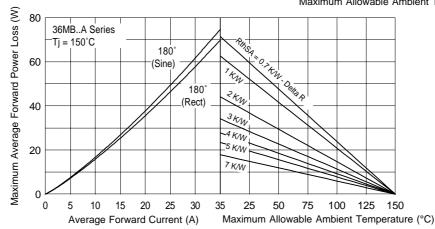


Fig. 3 - Total Power Loss Characteristics

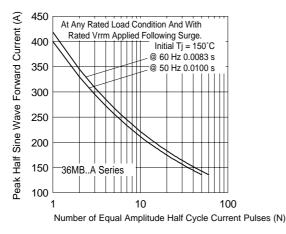


Fig. 9 - Maximum Non-Repetitive Surge Current

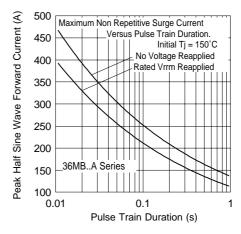


Fig. 10 - Maximum Non-Repetitive Surge Current

MB Series

Bulletin I2715 rev. I 03/03

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial and Consumer Level.

Qualification Standards can be found on IR's Web site.



IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 03/03